

ADD-A-PAK Generation VII Power Modules Thyristor/Thyristor, 75 A



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PRODUCT SUMMARY				
I _{T(AV)}	75 A			

MECHANICAL DESCRIPTION

The ADD-A-PAK generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- · High voltage
- Industrial standard package
- · Low thermal resistance
- UL approved file E78996
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- Up to 1600 V
- · High surge capability
- Easy mounting on heatsink

ELECTRICAL DESCRIPTION

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

MAJOR RATING	MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{T(AV)}	85 °C	75						
I _{T(RMS)}		115	Α					
1	50 Hz	1300	A					
I _{TSM}	60 Hz	1360						
l²t	50 Hz	8.45	kA ² s					
1-1	60 Hz	7.68	KA-S					
I ² √t		84.5	kA ² √s					
V _{RRM}	Range	400 to 1600	V					
T _{Stg}		- 40 to 125	°C					
TJ		- 40 (0 125						

VSKU71.., VSKV71.. Series

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ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM REPETITIVE PEAK OFF-STATE VOLTAGE, GATE OPEN CIRCUIT V	I _{RRM,} I _{DRM} AT 125 °C mA			
	04	400	500	400				
VSK.71	08	800	900	800	15			
VSR.71	12	1200	1300	1200	13			
	16	1600	1700	1600				

ON-STATE CONDUCTION							
PARAMETER	SYMBOL		TEST CONDITIONS				
Maximum average on-state current	I _{T(AV)}	180° conduction	180° conduction, half sine wave, $T_{C} = 85 ^{\circ}C$		75	^	
Maximum continuous RMS on-state current		DC			115	Α	
Maximum continuous RMS on-state current	I _{T(RMS)}	T _C			80	°C	
		t = 10 ms	No voltage		1300		
Maximum peak, one-cycle non-repetitive on-state current		t = 8.3 ms	reapplied	Sinusoidal	1360	^	
	I _{TSM}	t = 10 ms	100 % V _{RRM}	half wave, initial $T_J = T_J$ maximum	1093	Α	
		t = 8.3 ms	reapplied		1140		
		t = 10 ms	No voltage		8.45	kA ² s	
Maximum I ² t for fusing	I ² t	t = 8.3 ms	reapplied	Lateral Towns for the	7.68		
	I ² T	t = 10 ms	100 % V _{RRM}	Initial $T_J = T_J$ maximum	5.97		
		t = 8.3 ms	reapplied		5.45		
Maximum l²√t for fusing	I 2√t (1)	t = 0.1 ms to 1 $T_J = T_J \text{ maximu}$	84.5	kA²√s			
	. (2)	Low level (3)			0.96		
Maximum value of threshold voltage	V _{T(TO)} (2)	High level (4)	$T_J = T_J \text{ maxin}$	num	1.08	V	
Maximum value of on-state	(2)	Low level (3)			3.28	mΩ	
slope resistance	r _t ⁽²⁾	High level (4)	$T_J = T_J \text{ maxin}$	num	2.86		
Maximum on-state voltage drop	V_{TM}	$I_{TM} = \pi \times I_{T(AV)}$	T _J = 25 °C		1.72	V	
Maximum non-repetitive rate of rise of turned on current	dl/dt	$T_J = 25$ °C, from $I_{TM} = \pi \times I_{T(AV)}$,	150	A/µs			
Maximum holding current	I _H	$T_J = 25$ °C, and	$T_J = 25$ °C, anode supply = 6 V, resistive load, gate open circuit				
Maximum latching current	ΙL	T _J = 25 °C, and	ode supply = 6 \	/, resistive load	400		

Notes

 $^{^{(1)}}$ I²t for time t_{x} = I² \sqrt{t} x $\sqrt{t_{x}}$

⁽⁴⁾ $I > \pi \times I_{AV}$



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TRIGGERING						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
Maximum peak gate power	P_{GM}			12	١٨/	
Maximum average gate power	P _{G(AV)}			3.0	W	
Maximum peak gate current	I _{GM}			3.0	Α	
Maximum peak negative gate voltage	- V _{GM}			10		
		T _J = - 40 °C	Anode supply = 6 V resistive load	4.0	V	
Maximum gate voltage required to trigger	V_{GT}	T _J = 25 °C		2.5		
		T _J = 125 °C		1.7		
		T _J = - 40 °C		270		
Maximum gate current required to trigger	I _{GT}	T _J = 25 °C	Anode supply = 6 V resistive load	150	mA	
		T _J = 125 °C	- resistive load	80		
Maximum gate voltage that will not trigger	V_{GD}	T _J = 125 °C, rated V _{DRM} applied		0.25	V	
Maximum gate current that will not trigger	I_{GD}	$T_J = 125 ^{\circ}\text{C}$, rated V_{DR}	_M applied	6	mA	

BLOCKING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum peak reverse and off-state leakage current at V _{RRM} , V _{DRM}	I _{RRM,} I _{DRM}	T _J = 125 °C, gate open circuit	15	mA				
Maximum RMS insulation voltage	V _{INS}	50 Hz	3000 (1 min) 3600 (1 s)	V				
Maximum critical rate of rise of off-state voltage	dV/dt	T _J = 125 °C, linear to 0.67 V _{DRM}	1000	V/µs				

THERMAL AND MECHA	THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Junction operating and storage temperature range		T _J , T _{Stg}		- 40 to 125	°C		
Maximum internal thermal resistance, junction to case per leg		R _{thJC}	DC operation	0.29	°C/W		
Typical thermal resistance, case to heatsink per module		R _{thCS}	Mounting surface flat, smooth and greased	0.1			
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of	4	Nm		
but the but th			3 hours to allow for the spread of the compound.	3	Niii		
Approximate weight				75	g		
Approximate weight				2.7	OZ.		
Case style			JEDEC	TO-240AA	compatible		

△R CONDUCTION PER JUNCTION											
DEVICES	5	SINE HALF WAVE CONDUCTION					RECTANGULAR WAVE CONDUCTION				UNITS
DEVICES	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
VSK.71	0.052	0.062	0.079	0.116	0.197	0.037	0.064	0.085	0.121	0.200	°C/W

Note

• Table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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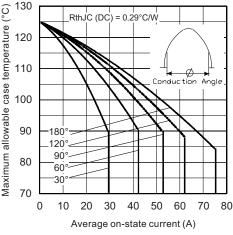


Fig. 1 - Current Ratings Characteristics

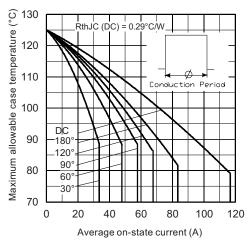


Fig. 2 - Current Ratings Characteristics

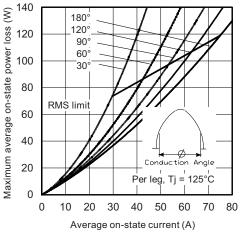


Fig. 3 - On-State Power Loss Characteristics

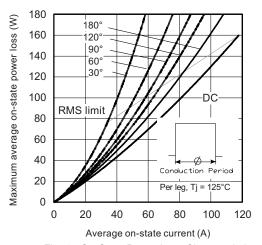


Fig. 4 - On-State Power Loss Characteristics

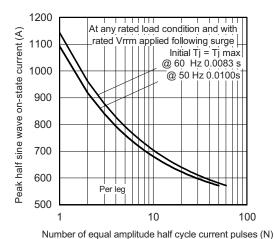


Fig. 5 - Maximum Non-Repetitive Surge Current

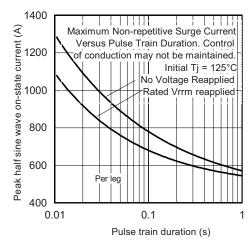


Fig. 6 - Maximum Non-Repetitive Surge Current



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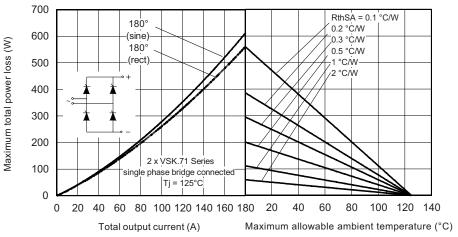


Fig. 7 - On-State Power Loss Characteristics

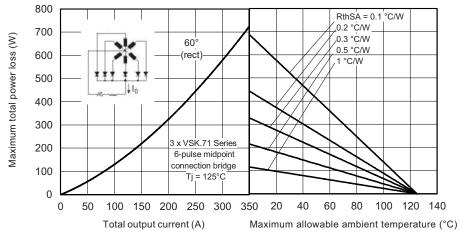


Fig. 8 - On-State Power Loss Characteristics

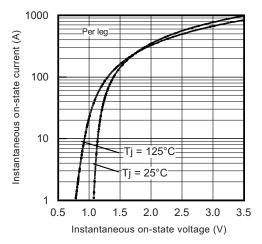


Fig. 9 - On-State Voltage Characteristics

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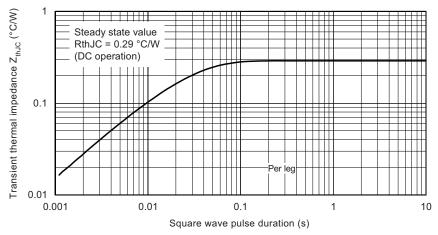
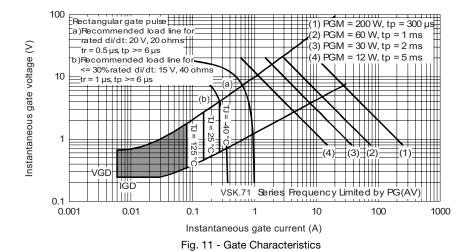
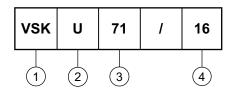


Fig. 10 - Thermal Impedance Z_{thJC} Characteristics



ORDERING INFORMATION TABLE

Device code



- Module type
- 2 Circuit configuration (see end of datasheet)
- 3 Current code (75 A)
- Voltage code (see Voltage Ratings table)

Note

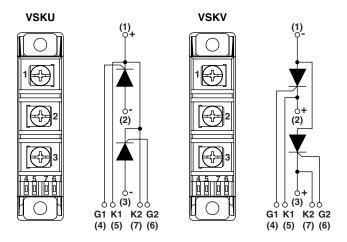
• To order the optional hardware go to www.vishay.com/doc?95172





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CIRCUIT CONFIGURATION

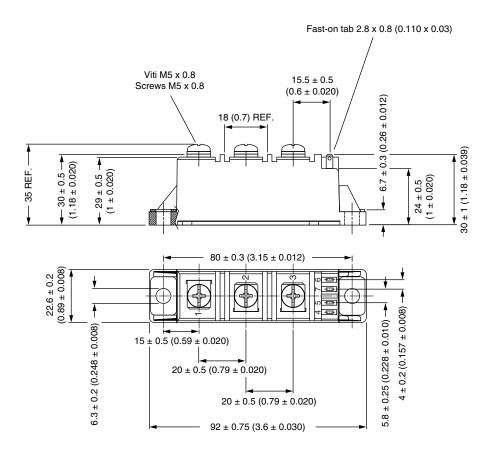


LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95368			



ADD-A-PAK Generation VII - Thyristor

DIMENSIONS in millimeters (inches)





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